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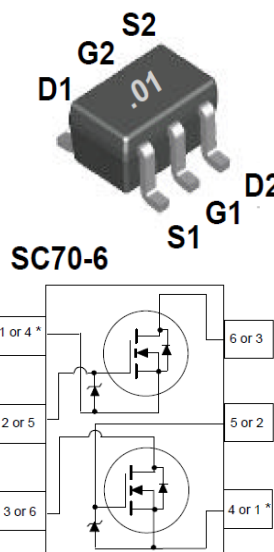
April 2016

## FDG6301N\_F085

### Dual N-Channel, Digital FET

#### Features

- 25 V, 0.22 A continuous, 0.65 A peak.
- $R_{DS(ON)} = 4 \Omega @ V_{GS} = 4.5 \text{ V}$ ,
- $R_{DS(ON)} = 5 \Omega @ V_{GS} = 2.7 \text{ V}$ .
- Very low level gate drive requirements allowing direct operation in 3 V circuits ( $V_{GS(th)} < 1.5 \text{ V}$ ).
- Gate-Source Zener for ESD ruggedness ( $>6\text{kV}$  Human Body Model).
- Compact industry standard SC70-6 surface mount package.
- Qualified to AEC Q101
- RoHS Compliant



#### Applications

- Low voltage applications as a replacement for bipolar digital transistors and small signal MOSFETs

#### MOSFET Maximum Ratings $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{DSS}$	Drain to Source Voltage	25	V
$V_{GS}$	Gate to Source Voltage	8	V
$I_D$	Drain Current Continuous	0.22	A
	Pulsed	0.65	
$P_D$	Power Dissipation	0.3	W
$T_J, T_{STG}$	Operating and Storage Temperature	-55 to +150	$^\circ\text{C}$
ESD	Electrostatic Discharge Rating MIL-STD-883D Human Body Model(100 pF / 1500 W)	6.0	kV
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	415	$^\circ\text{C/W}$

#### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDG6301N	FDG6301N_F085	SC70-6	7"	8mm	3000 units

#### Notes:

- 1:  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design, while  $R_{\theta JA}$  is determined by the board design.  $R_{\theta JA} = 415^\circ\text{C/W}$  on minimum pad mounting on FR-4 board in still air
- 2: A suffix as "...F085P" has been temporarily introduced in order to manage a double source strategy as Fairchild has officially announced in Aug 2014.
- 3: Pulse Test: Pulse Width  $< 300\mu\text{s}$ , Duty Cycle  $< 2.0\%$ .

FDG6301N\_F085 Dual N-Channel Digital FET

**Electrical Characteristics**  $T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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**Off Characteristics**

$B_{V_{DSS}}$	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}$ , $V_{GS} = 0\text{V}$	25	-	-	V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 20\text{V}$ , $V_{GS} = 0\text{V}$ $T_J = 55^\circ\text{C}$	-	-	1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 8\text{V}$	-	-	$\pm 100$	nA

**On Characteristics**

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250\mu\text{A}$	0.65	0.85	1.5	V
$r_{DS(on)}$	Drain to Source On Resistance	$I_D = 0.22\text{A}$ , $V_{GS} = 4.5\text{V}$	-	2.6	4	$\Omega$
		$I_D = 0.19\text{A}$ , $V_{GS} = 2.7\text{V}$	-	3.7	5	
		$I_D = 0.22\text{A}$ , $V_{GS} = 4.5\text{V}$ $T_J = 125^\circ\text{C}$	-	5.3	7	
$I_{D(on)}$	On-State Drain Current	$V_{GS} = 4.5\text{V}$ , $V_{DS} = 5\text{V}$	0.22	-	-	
$g_{FS}$	Forward Transconductance	$I_D = 0.22\text{A}$ , $V_{DS} = 5\text{V}$	-	0.2	-	S

**Dynamic Characteristics**

$C_{iss}$	Input Capacitance	$V_{DS} = 10\text{V}$ , $V_{GS} = 0\text{V}$ , $f = 1\text{MHz}$	-	9.5	-	pF
$C_{oss}$	Output Capacitance		-	6	-	pF
$C_{rss}$	Reverse Transfer Capacitance		-	1.3	-	pF
$Q_{g(TOT)}$	Total Gate Charge at -4.5V	$V_{GS} = 0$ to $4.5\text{V}$	-	0.29	0.4	nC
$Q_{gs}$	Gate to Source Gate Charge	$V_{DD} = 5\text{V}$ $I_D = 0.22\text{A}$	-	0.12	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge		-	0.03	-	nC

**Switching Characteristics**

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 5\text{V}$ , $I_D = 0.5\text{A}$ $V_{GS} = 4.5\text{V}$ , $R_{GEN} = 50\Omega$	-	5	10	ns
$t_r$	Rise Time		-	4.5	10	ns
$t_{d(off)}$	Turn-Off Delay Time		-	4	8	ns
$t_f$	Fall Time		-	3.2	7	ns

**Drain-Source Diode Characteristics**

I <sub>S</sub>	Maximum Continuous Source Current		-	-	0.25	A
V <sub>SD</sub>	Source to Drain Diode Voltage	I <sub>SD</sub> = 0.25A, V <sub>GS</sub> = 0V	-	0.8	1.2	V

## Typical Characteristics

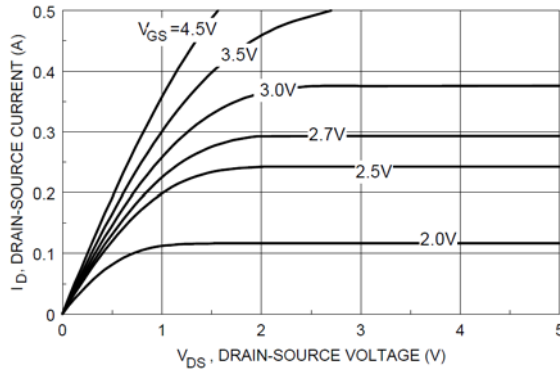


Figure 1. On-Region Characteristics.

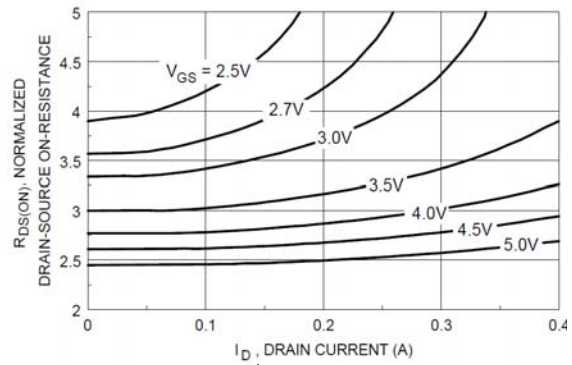


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

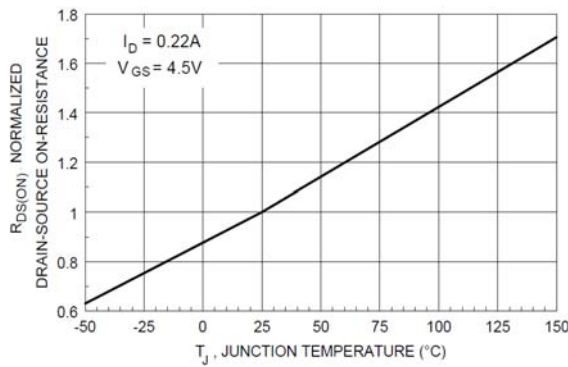


Figure 3. On-Resistance Variation with Temperature.

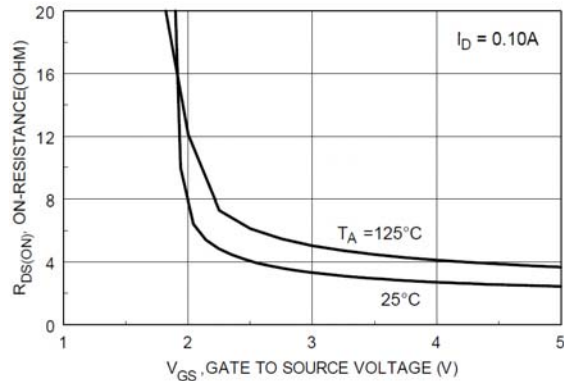


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

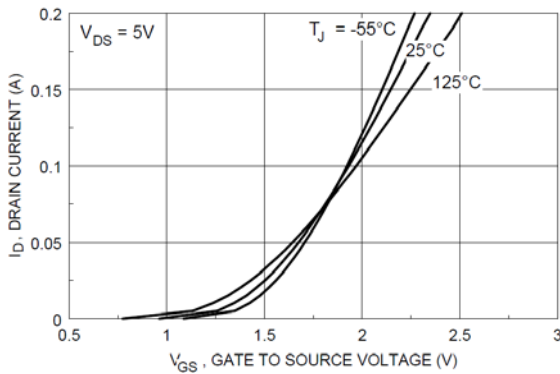


Figure 5. Transfer Characteristics.

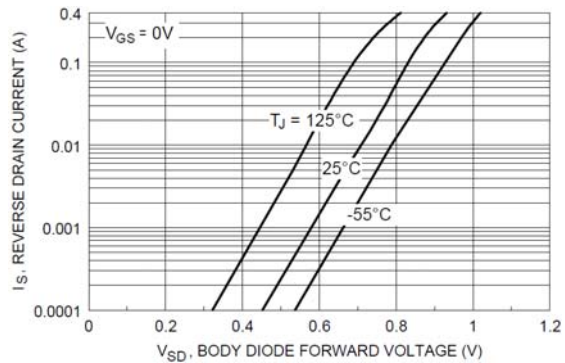


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

## Typical Characteristics

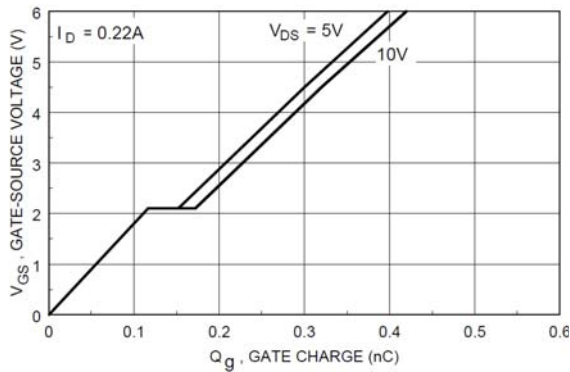


Figure 7. Gate Charge Characteristics.

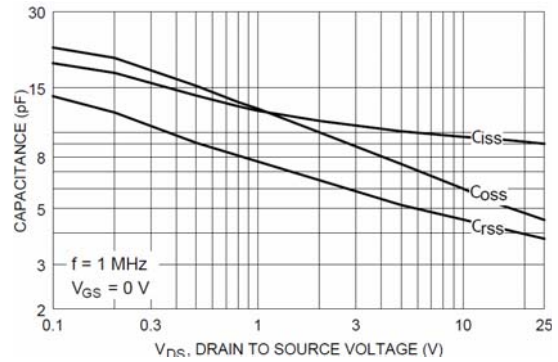


Figure 8. Capacitance Characteristics.

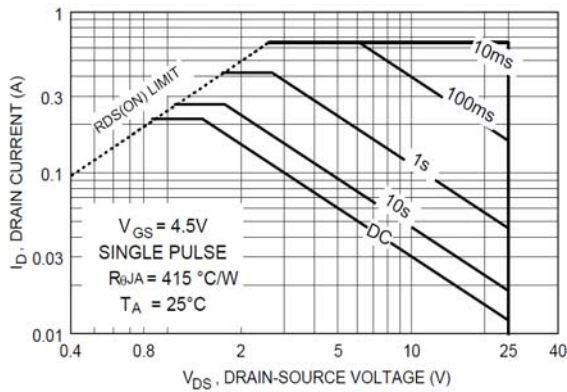


Figure 9. Maximum Safe Operating Area.

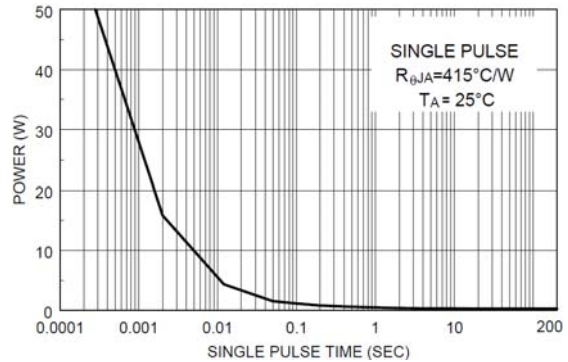


Figure 10. Single Pulse Maximum Power Dissipation.

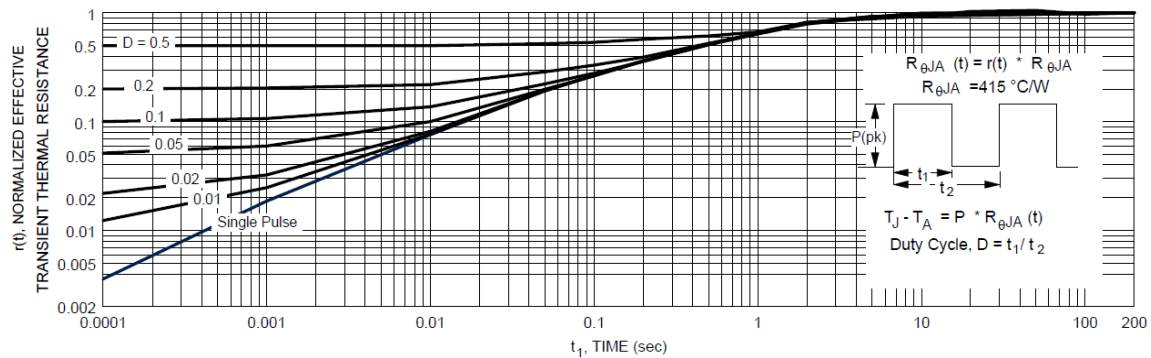
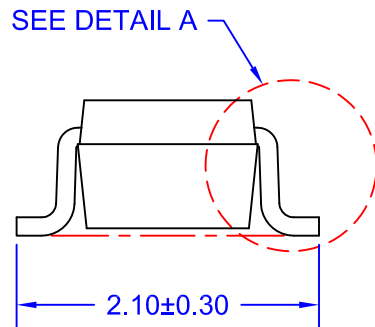
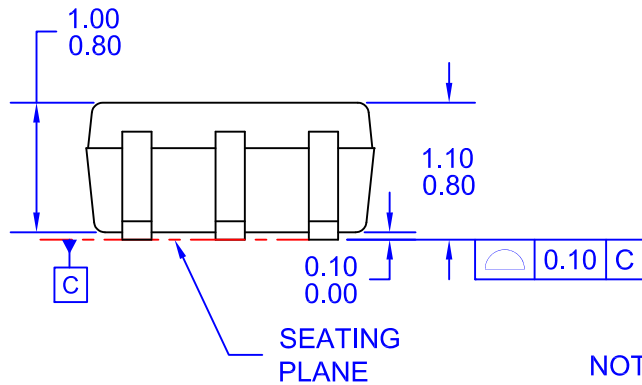
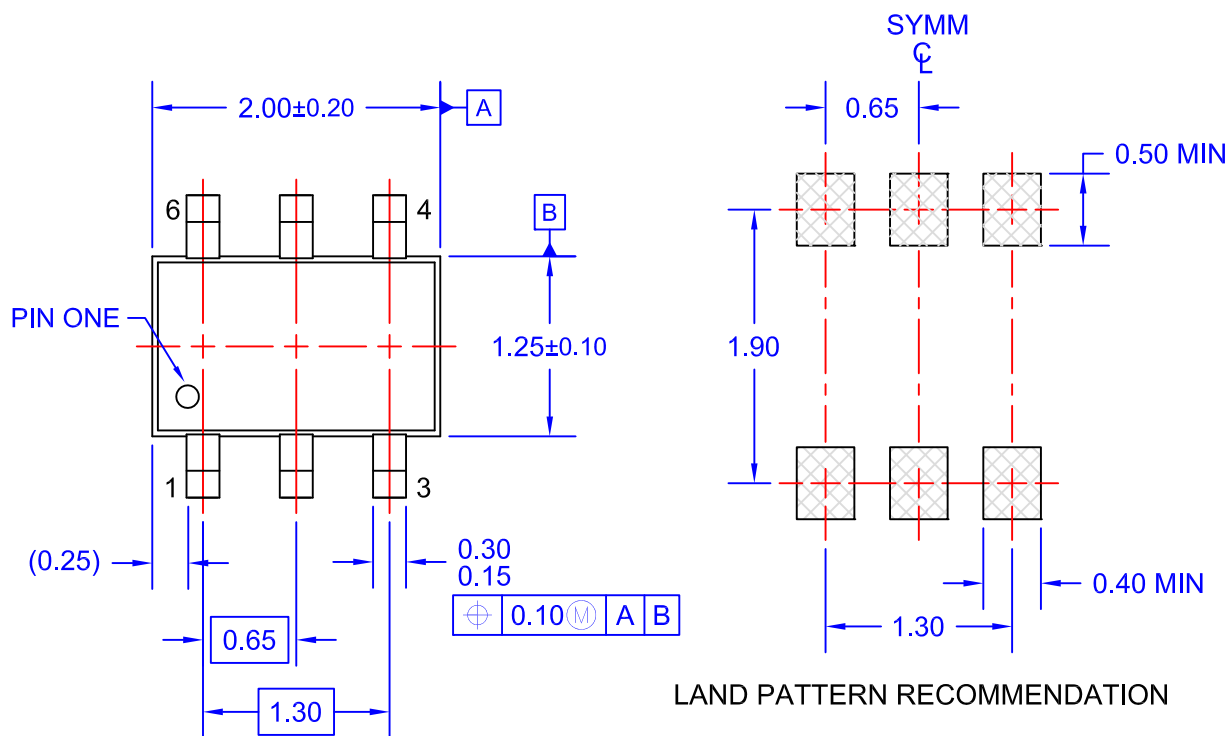
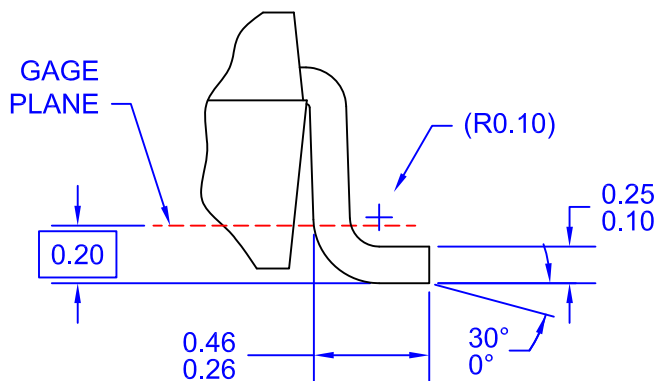


Figure 11. Transient Thermal Response Curve.



- NOTES: UNLESS OTHERWISE SPECIFIED
- A) THIS PACKAGE CONFORMS TO EIAJ SC-88, 1996.
  - B) ALL DIMENSIONS ARE IN MILLIMETERS.
  - C) DIMENSIONS DO NOT INCLUDE BURRS OR MOLD FLASH.
  - D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M-2009
  - E) DRAWING FILENAME: MKT-MAA06AREV7



DETAIL A  
SCALE: 60X



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